

EM MICROELECTRONIC

A COMPANY OF THE SWATCH GROUP

FACT SHEET | EM4324

Subject to change without notice Version 1.0, 7-Oct-14 Copyright © 2014, EM Microelectronic-Marin SA www.emmicroelectronic.com



General Description

EM4324 is a Gen2 long range passive / battery-assisted passive UHF RFID tag IC compliant with the ISO 18000-63 / EPCglobal Gen-2 protocol. The chip offers an advanced feature set (EPC+) leading to a performance beyond that of standard Gen2 chips. Battery-assisted, EM4324 offers superior reading range and reliability compared to purely passive RFID solutions. The battery- assisted mode is tailored to harsh environment applications where other passive UHF solutions fail e.g. in the presence of water or metal.

The EM4324 current consumption has been optimized to maximize battery lifetime. Even if the battery is flat, the chip continues to operate and communicate with the reader in passive mode.

The memory size is 1024 bits enabling support of ISO or EPC data structures. Each chip is delivered with a 64-bit Unique Identifier to ensure full traceability.

The EM4324 includes a tamper detection circuit to support E-seal applications. Tamper detection can be implemented using a simple continuity loop, with heat sensitive fuse wire, with sensors having both high and low impedance states, or with external devices controlling an electronic switch such as a MOSFET.

Applications

- I Supply chain management
- I Tracking and tracing
- I Containers identification
- Access control
- Asset control
- E-seals

Ordering Information

The versions below are considered standards and should be readily available. For other versions or other delivery form, please contact EM Microelectronic-Marin S.A. For samples, please, order exclusively from the standard version.

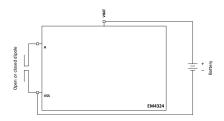
| Part Number | Tamper | Package / | Delivery Form |
|-----------------|-----------|---------------------------|---------------|
| | Detection | Die Form | |
| EM4324V1WS7E | No | Sawn wafer / bumped die - | Wafer sawn on |
| | | 7 mils thickness | frame |
| EM4324V1WS7E | Yes | Sawn wafer / bumped die - | Wafer sawn on |
| | | 7 mils thickness | frame |
| EM4324VXYYY-%%% | | Custom | Custom |

1 kbit Read/Write, ISO 18000-63 / EPC[™] Gen2 **Passive / Battery-assisted** Passive Contactless IC

Features

- I ISO 18000-63 compliant
- I EPC Gen-2 compliant
- | 1024-bit non-volatile memory
- | 720-bit user's free memory
- 1 96-bit EPC numbers supported
- | 64-bit manufacturer-programmed Unique Identifier (TID / UID)
- I Tamper detection
- I Battery assistance mode for unsurpassed reading range and reading reliability
- Rectifier that allows passive operation in case the battery is flat or not present
- | 32-bit password-protected Kill command
- I 32-bit password-protected Access command
- Anti-tearing feature to prevent malicious unlocking
- Extended temperature range (-20°C to +85°C)
- I Available also in TSSOP-8 package

Typical Configuration



IC Block Diagram

